

BC107,A,B
BC108B,C
BC109B,C

NPN SILICON TRANSISTOR



TO-18 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR BC107, BC108, BC109 series types are small signal NPN silicon transistors, manufactured by the epitaxial planar process, designed for general purpose amplifier applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

| | | | | | |
|--|----------------|-----|-------------|-----|---------------------------|
| Collector-Base Voltage | V_{CB0} | 50 | 30 | 30 | V |
| Collector-Emitter Voltage | V_{CEO} | 45 | 25 | 25 | V |
| Emitter-Base Voltage | V_{EBO} | 6.0 | 5.0 | 5.0 | V |
| Continuous Collector Current | I_C | | 200 | | mA |
| Power Dissipation | P_D | | 600 | | mW |
| Operating and Storage Junction Temperature | T_J, T_{stg} | | -65 to +200 | | $^\circ\text{C}$ |
| Thermal Resistance | θ_{JC} | | 175 | | $^\circ\text{C}/\text{W}$ |

| SYMBOL | BC107 | BC108 | BC109 | UNITS |
|----------------|-------|-------------|-------|---------------------------|
| V_{CB0} | 50 | 30 | 30 | V |
| V_{CEO} | 45 | 25 | 25 | V |
| V_{EBO} | 6.0 | 5.0 | 5.0 | V |
| I_C | | 200 | | mA |
| P_D | | 600 | | mW |
| T_J, T_{stg} | | -65 to +200 | | $^\circ\text{C}$ |
| θ_{JC} | | 175 | | $^\circ\text{C}/\text{W}$ |

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

| SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|---------------|--|------|-----|------|---------------|
| I_{CBO} | $V_{CB}=45\text{V}$ (BC107) | | | 15 | nA |
| I_{CBO} | $V_{CB}=45\text{V}, T_A=125^\circ\text{C}$ (BC107) | | | 4.0 | μA |
| I_{CBO} | $V_{CB}=25\text{V}$ (BC108, BC109) | | | 15 | nA |
| I_{CBO} | $V_{CB}=25\text{V}, T_A=125^\circ\text{C}$ (BC108, BC109) | | | 4.0 | μA |
| BV_{CEO} | $I_C=2.0\text{mA}$ (BC107) | 45 | | | V |
| BV_{CEO} | $I_C=2.0\text{mA}$ (BC108, BC109) | 25 | | | V |
| BV_{EBO} | $I_E=10\mu\text{A}$ (BC107) | 6.0 | | | V |
| BV_{EBO} | $I_E=10\mu\text{A}$ (BC108, BC109) | 5.0 | | | V |
| $V_{CE(SAT)}$ | $I_C=10\text{mA}, I_B=0.5\text{mA}$ | | | 0.25 | V |
| $V_{CE(SAT)}$ | $I_C=100\text{mA}, I_B=5.0\text{mA}$ | | | 0.6 | V |
| $V_{BE(SAT)}$ | $I_C=10\text{mA}, I_B=0.5\text{mA}$ | | 0.7 | 0.83 | V |
| $V_{BE(SAT)}$ | $I_C=100\text{mA}, I_B=5.0\text{mA}$ | | 1.0 | 1.05 | V |
| $V_{BE(ON)}$ | $V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ | 0.55 | | 0.7 | V |
| $V_{BE(ON)}$ | $V_{CE}=5.0\text{V}, I_C=10\text{mA}$ | | | 0.77 | V |
| h_{FE} | $V_{CE}=5.0\text{V}, I_C=10\mu\text{A}$ (BC107B, BC108B, BC109B) | 40 | | | |
| h_{FE} | $V_{CE}=5.0\text{V}, I_C=10\mu\text{A}$ (BC108C, BC109C) | 100 | | | |
| h_{FE} | $V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ (BC107) | 110 | | 450 | |
| h_{FE} | $V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ (BC107A) | 110 | | 220 | |
| h_{FE} | $V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ (BC107B, BC108B, BC109B) | 200 | | 450 | |
| h_{FE} | $V_{CE}=5.0\text{V}, I_C=2.0\text{mA}$ (BC108C, BC109C) | 420 | | 800 | |

R1 (16-August 2012)

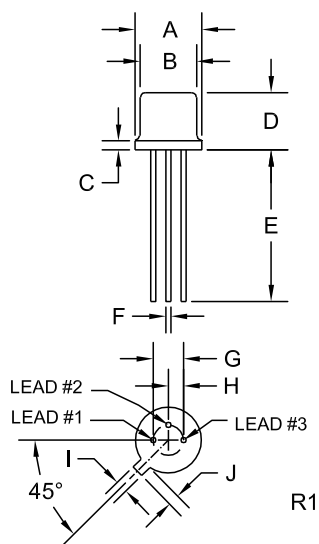
BC107,A,B
BC108B,C
BC109B,C

NPN SILICON TRANSISTOR

ELECTRICAL CHARACTERISTICS - Continued: ($T_A=25^\circ\text{C}$ unless otherwise noted)

| SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|----------|---|-----|-----|-----|-------|
| h_{fe} | $V_{CE}=5.0\text{V}$, $I_C=2.0\text{mA}$, $f=1.0\text{kHz}$ (BC107) | 125 | | 500 | |
| h_{fe} | $V_{CE}=5.0\text{V}$, $I_C=2.0\text{mA}$, $f=1.0\text{kHz}$ (BC107A) | 125 | | 260 | |
| h_{fe} | $V_{CE}=5.0\text{V}$, $I_C=2.0\text{mA}$, $f=1.0\text{kHz}$ (BC107B, BC108B, BC109B) | 240 | | 500 | |
| h_{fe} | $V_{CE}=5.0\text{V}$, $I_C=2.0\text{mA}$, $f=1.0\text{kHz}$ (BC108C) | | 500 | | |
| h_{fe} | $V_{CE}=5.0\text{V}$, $I_C=2.0\text{mA}$, $f=1.0\text{kHz}$ (BC109C) | 450 | | 900 | |
| f_T | $V_{CE}=5.0\text{V}$, $I_C=10\text{mA}$, $f=100\text{MHz}$ | 150 | | | MHz |
| C_{ob} | $V_{CB}=10\text{V}$, $I_E=0$, $f=1.0\text{MHz}$ | | | 4.5 | pF |
| NF | $V_{CE}=5.0\text{V}$, $I_C=0.2\text{mA}$, $R_g=2.0\text{k}\Omega$, $B=200\text{Hz}$, $f=1.0\text{kHz}$ (BC107, BC108) | | | 10 | dB |
| NF | $V_{CE}=5.0\text{V}$, $I_C=0.2\text{mA}$, $R_g=2.0\text{k}\Omega$, $B=200\text{Hz}$, $f=1.0\text{kHz}$ (BC109) | | | 4.0 | dB |

TO-18 CASE - MECHANICAL OUTLINE



| SYMBOL | DIMENSIONS | | | |
|---------|------------|-------|-------------|------|
| | INCHES | | MILLIMETERS | |
| | MIN | MAX | MIN | MAX |
| A (DIA) | 0.209 | 0.230 | 5.31 | 5.84 |
| B (DIA) | 0.178 | 0.195 | 4.52 | 4.95 |
| C | - | 0.030 | - | 0.76 |
| D | 0.170 | 0.210 | 4.32 | 5.33 |
| E | 0.500 | - | 12.70 | - |
| F (DIA) | 0.016 | 0.019 | 0.41 | 0.48 |
| G (DIA) | 0.100 | | 2.54 | |
| H | 0.050 | | 1.27 | |
| I | 0.036 | 0.046 | 0.91 | 1.17 |
| J | 0.028 | 0.048 | 0.71 | 1.22 |

TO-18 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING:
FULL PART NUMBER

R1 (16-August 2012)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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